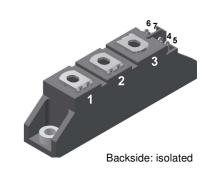
Thyristor Module

MCC19-08io1B

| V_{RRM} | <i>=</i> 2x | 800 V |
|------------------|-------------|--------|
| I _{tav} | = | 18 A |
| Vτ | = | 1.57 V |

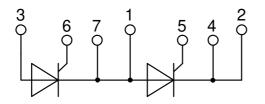
Phase leg

Part number MCC19-08io1B





20161222b



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: TO-240AA

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Terms and Conditions of Usage

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

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MCC19-08io1B

| Symbol | Definition | Conditions | | min. | typ. | max. | Uni |
|-----------------------|------------------------------------|---|--------------------------------------|------|------|------|------------------|
| V _{RSM/DSM} | max. non-repetitive reverse/forwa | | $T_{vJ} = 25^{\circ}C$ | | typ. | 900 | 0111 \ |
| V _{RRM/DRM} | max. repetitive reverse/forward b | | $T_{vJ} = 25^{\circ}C$ | | | 800 | ١ |
| | reverse current, drain current | $V_{B/D} = 800 \text{ V}$ | $T_{vJ} = 25^{\circ}C$ | | | 100 | μΑ |
| ■ R/D | | $V_{\rm R/D} = 800 V$ | T _{vJ} = 125°C | | | 3 | mA |
| V _T | forward voltage drop | $I_{\rm T} = 40 \text{A}$ | $T_{v,i} = 25^{\circ}C$ | | | 1.56 | ۱۱۱ |
| ▼т | lonnara vonago arop | $I_{\rm T} = 80 {\rm A}$ | 1 _{VJ} = 20 0 | | | 2.05 | ١ |
| | | $\frac{I_{+}}{I_{-}} = 40 \text{ A}$ | T _{v.i} = 125°C | | | 1.57 | ۷ |
| | | $I_{\rm T} = 80 {\rm A}$ | 1,03 = 120 0 | | | 2.29 | ١ |
| ITAV | average forward current | $\frac{T_{c}}{T_{c}} = 85^{\circ}C$ | T _{v.1} = 125°C | | | 18 | A |
| I _{T(RMS)} | RMS forward current | 180° sine | · vj | | | 28 | A |
| V _{T0} | threshold voltage | | T _{v.1} = 125°C | | | 0.85 | ١ |
| r _T | slope resistance { for power le | oss calculation only | · vj · · _ · · · | | | 18 | mΩ |
| R _{thJC} | thermal resistance junction to cas | 20 C | | | | 1.3 | K/W |
| R _{thCH} | thermal resistance case to heatsi | | | | 0.20 | | K/W |
| P _{tot} | total power dissipation | | $T_c = 25^{\circ}C$ | | 0.20 | 77 | W |
| I _{TSM} | max. forward surge current | t = 10 ms; (50 Hz), sine | $T_{v,i} = 45^{\circ}C$ | | | 400 | A |
| - 151 | 0 | t = 8,3 ms; (60 Hz), sine | $V_{\rm R} = 0 V$ | | | 430 | A |
| | | t = 10 ms; (50 Hz), sine | T _{v.I} = 125°C | | | 340 | A |
| | | t = 8,3 ms; (60 Hz), sine | $V_{\rm R} = 0 V$ | | | 365 | A |
| l²t | value for fusing | t = 10 ms; (50 Hz), sine | $T_{\rm VJ} = 45^{\circ}\rm C$ | | | 800 | A ² s |
| | C C | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 770 | A ² s |
| | | t = 10 ms; (50 Hz), sine | T _{v.I} = 125°C | | | 580 | A ² s |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 555 | A ² s |
| C | junction capacitance | $V_{B} = 400 V f = 1 MHz$ | $T_{vJ} = 25^{\circ}C$ | | 22 | | pF |
| P _{GM} | max. gate power dissipation | t _P = 30 μs | $T_{c} = 125^{\circ}C$ | | | 10 | W |
| | | t _P = 300 μs | | | | 5 | W |
| P _{GAV} | average gate power dissipation | | | | | 0.5 | W |
| (di/dt) _{cr} | critical rate of rise of current | T _{v.i} = 125 °C; f = 50 Hz re | epetitive, $I_{T} = 45 \text{ A}$ | | | 150 | A/μs |
| | | $t_{P} = 200 \mu s; di_{G}/dt = 0.45 A/\mu s; -$ | • · · · | | | | |
| | | $I_{G} = 0.45 \text{ A}; V = \frac{2}{3} V_{DRM}$ no | on-repet., $I_{\tau} = 18 \text{ A}$ | | | 500 | A/μs |
| (dv/dt) _{cr} | critical rate of rise of voltage | $V = \frac{2}{3} V_{DBM}$ | T _{vJ} = 125°C | | | 1000 | V/µs |
| | | R _{GK} = ∞; method 1 (linear volta | ge rise) | | | | |
| V _{GT} | gate trigger voltage | $V_{D} = 6 V$ | $T_{vJ} = 25^{\circ}C$ | | | 1.5 | ٧ |
| | | | $T_{vJ} = -40 ^{\circ}\text{C}$ | | | 1.6 | V |
| I _{GT} | gate trigger current | $V_{D} = 6 V$ | $T_{vJ} = 25^{\circ}C$ | | | 100 | mA |
| | | | $T_{vJ} = -40 ^{\circ}\text{C}$ | | | 200 | mA |
| V _{gd} | gate non-trigger voltage | $V_{\rm D} = \frac{2}{3} V_{\rm DRM}$ | T _{vJ} = 125°C | | | 0.2 | ٧ |
| I _{gd} | gate non-trigger current | | | | | 5 | mA |
| IL | latching current | t _p = 10 μs | $T_{vJ} = 25 ^{\circ}C$ | | | 450 | mA |
| | | $I_{\rm G} = 0.45 \text{A}; \text{di}_{\rm G}/\text{dt} = 0.45 \text{A}/\mu\text{s}$ | 3 | | | | |
| I _H | holding current | $V_{D} = 6 V R_{GK} = \infty$ | $T_{vJ} = 25 \degree C$ | | | 200 | mA |
| t _{gd} | gate controlled delay time | $V_{D} = \frac{1}{2} V_{DRM}$ | $T_{vJ} = 25 ^{\circ}C$ | | | 2 | με |
| | | $I_{G} = 0.45 \text{ A}; \ di_{G}/dt = 0.45 \text{ A}/\mu s$ | 3 | | | | |
| t _q | turn-off time | $V_{R} = 100 \text{ V}; I_{T} = 20 \text{ A}; \text{ V} = \frac{2}{3}$ | | | 150 | | με |
| | | $di/dt = 10 \text{ A}/\mu \text{s} dv/dt = 20 \text{ V}$ | | | | | |

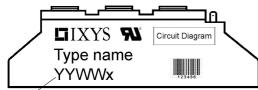
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MCC19-08io1B

| Package | TO-240AA | | | | F | Ratings | S | |
|-----------------------------|---|--------------------------------|-----------------------------|------|------|---------|------|------|
| Symbol | Definition | Conditions | | | min. | typ. | max. | Unit |
| | RMS current | per terminal | | | | | 200 | Α |
| T _{vj} | virtual junction temperature | | | | -40 | | 125 | °C |
| T _{op} | operation temperature | | | | -40 | | 100 | °C |
| T _{stg} | storage temperature | | | | -40 | | 125 | °C |
| Weight | | | | | | 81 | | g |
| M _D | mounting torque | | | | 2.5 | | 4 | Nm |
| M _T | terminal torque | | | | 2.5 | | 4 | Nm |
| d _{Spp/App} | creepage distance on surface striking distance throug | | terminal to terminal | 13.0 | 9.7 | | | mm |
| d _{Spb/Apb} | creepage distance on surrac | e Sunking distance unough an | terminal to backside | 16.0 | 16.0 | | | mm |
| V | isolation voltage | t = 1 second | | | 3600 | | | V |
| | | t = 1 minute | 50/60 Hz, RMS; liso∟ ≤ 1 mA | | 3000 | | | v |



Date Code

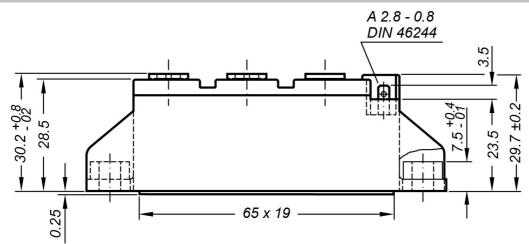
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | MCC19-08io1B | MCC19-08io1B | Box | 36 | 452807 |

| Similar Part | Package | Voltage class |
|---------------|-------------|---------------|
| MCMA25P1200TA | TO-240AA-1B | 1200 |
| MCMA35P1200TA | TO-240AA-1B | 1200 |

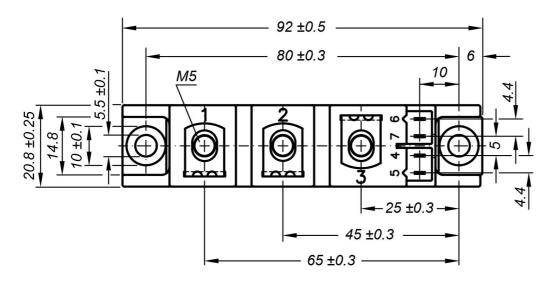
| Equivalent Circuits for Simulation | | | * on die level | T _{vj} = 125 °C |
|------------------------------------|--------------------|-----------|----------------|--------------------------|
| | R₀ | Thyristor | | |
| V _{0 max} | threshold voltage | 0.85 | | V |
| $\mathbf{R}_{0 \max}$ | slope resistance * | 16.8 | | mΩ |

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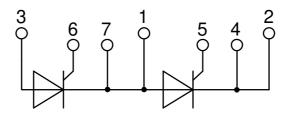
Outlines TO-240AA



General tolerance: DIN ISO 2768 class "c"



Optional accessories: Keyed gate/cathode twin plugs Wire length: 350 mm, gate = white, cathode = red UL 758, style 3751 Type **ZY 200L** (L = Left for pin pair 4/5) Type **ZY 200R** (R = Right for pin pair 6/7)



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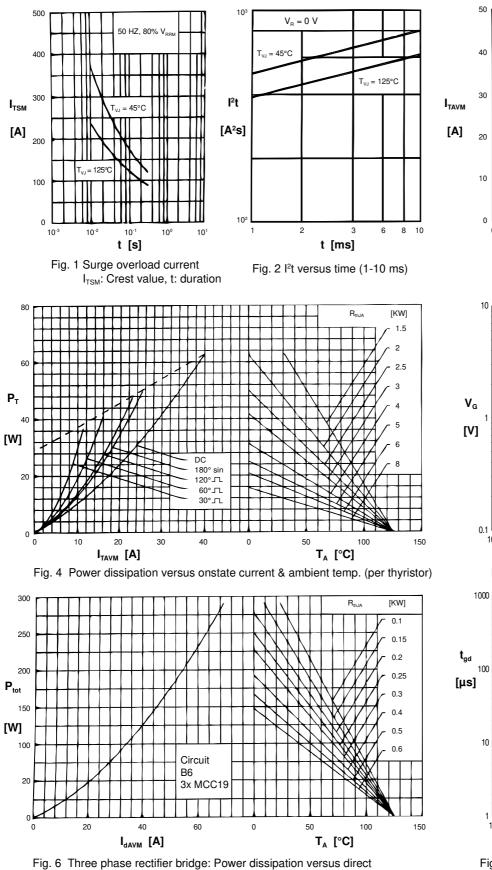
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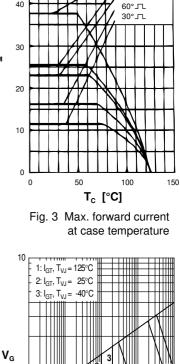
LIXYS

DC

180° sin 120°-7⊂

Thyristor





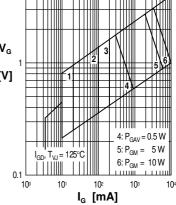


Fig. 5 Gate trigger charact.

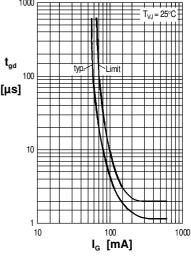


Fig. 7 Gate trigger delay time

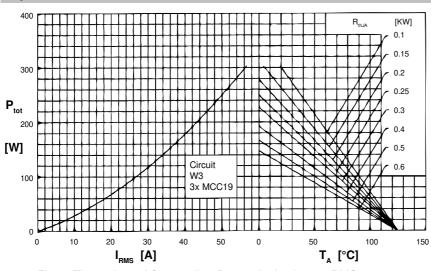
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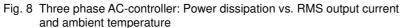


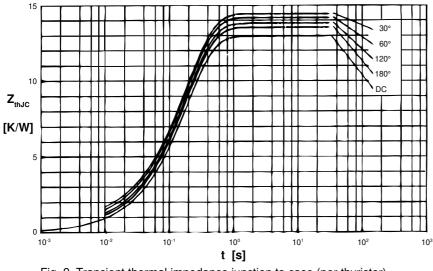
output current and ambient temperature

MCC19-08io1B

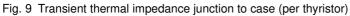
Thyristor

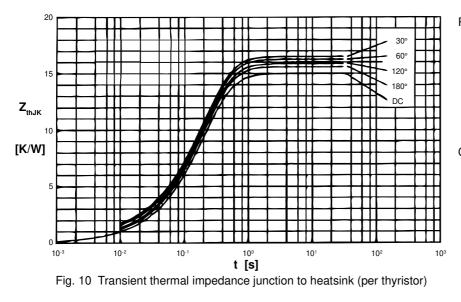






| $R_{_{thJ}}$ | _{ic} for varie | ous conduction angles d: | | | | |
|--------------|--|--------------------------|--|--|--|--|
| | d R _t | _{,JC} [K/W] | | | | |
| | DC | 1.30 | | | | |
| | 180° | 1.35 | | | | |
| | 120° | 1.39 | | | | |
| | 60° | 1.42 | | | | |
| | 30° | 1.45 | | | | |
| Cor | Constants for $Z_{th,IC}$ calculation: | | | | | |
| i | R _{thi} [K/W |] t _i [s] | | | | |
| 1 | 0.018 | 0.0033 | | | | |
| 2 | 0.041 | 0.0216 | | | | |
| 3 | 1.241 | 0.1910 | | | | |





| $R_{{}_{thJ\!K}}$ for various conduction angles d: | | | | | | |
|--|---------------------------------------|-----------------------|--|--|--|--|
| | d R | _{thJK} [K/W] | | | | |
| | DC | 1.50 | | | | |
| | 180° | 1.55 | | | | |
| | 120° | 1.59 | | | | |
| | 60° | 1.62 | | | | |
| | 30° | 1.65 | | | | |
| Cor | Constants for Z_{thJK} calculation: | | | | | |
| i | R _{thi} [K/V | V] t _i [s] | | | | |
| 1 | 0.018 | 0.0033 | | | | |
| 2 | 0.041 | 0.0216 | | | | |
| 3 | 1.241 | 0.1910 | | | | |

0.4600

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0.200